



Substitute for form PTO-146A, 1-98, PATENT WORKSHEET

INFORMATION DISCLOSURE STATEMENT BY APPLICANT

(use as many sheets as necessary)

Sheet

1

of

1

Complete if Known

Application Number	09/295,607
Filing Date	April 22, 1999
First Named Inventor	Shunpei YAMAZAKI
Art Unit	2811
Examiner Name	Steven Ho Yin Loke
Attorney Docket Number	740756-1961

U.S. PATENT DOCUMENTS

Examiner Initials ¹	Cite No. ¹	U.S. Patent Document		Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
		Number - Kind Code ² (if known)	Kind Code ³ (if known)			
Loke		US-4,832,986		05-23-1989	Gladfelter et al.	
Loke		US-5,192,644		03-09-1993	Ohta et al.	

FOREIGN PATENT DOCUMENTS

Examiner Initials ¹	Cite No. ¹	Foreign Patent Document		Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	T ⁴
		Country Code ⁵ Number ⁴	Kind Code ³ (if known)				
Loke		JP 58-085520		05-21-1983	Koba		Abstract
Loke		JP 62-214669		09-21-1987	Kaneko et al.		Abstract
Loke		JP 02-033935		02-05-1990	Yazaki		Abstract
Loke		JP 03-175632		07-30-1991	Fujiki et al.		Abstract
Loke		JP 04-139727		05-13-1992	Matsumoto et al.		Abstract

OTHER PRIOR ART – NON PATENT LITERATURE DOCUMENTS

Examiner Initials ¹	Cite No. ¹	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T ²
Loke		HSIEH, J.J., ET AL., "DIRECTIONAL DEPOSITION OF DIELECTRIC SILICON OXIDE BY PLASMA ENHANCED TEOS PROCESS", VMIC CONFERENCE, PP. 411-415	

Examiner Signature	Loke	Date Considered	3/2/04
--------------------	------	-----------------	--------

*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

¹ Applicant's unique citation designation number (optional). ² See Kinds Codes of USPTO Patent Documents at www.uspto.gov or MPEP 901.04. ³ Enter Office that issued the document, by the two-letter code (WIPO Standard ST.3). ⁴ For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the serial number of the patent document. ⁵ Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST.16 if possible. ⁶ Applicant is to place a check mark here if English language Translation is attached.

¹ Applicant's unique citation designation number (optional). ² Applicant is to place a check mark here if English language Translation is attached.

BEST AVAILABLE COPY

RECEIVED
JAN - 7 2004
TECHNOLOGY CENTER 2800